

**HFB20HJ20C**

Ultrafast, Soft Recovery Diode

**Features**

- Reduced RFI and EMI
- Reduced Snubbing
- Extensive Characterization of Recovery Parameters
- Hermetic
- Surface Mount

$V_R = 200V$
$I_{F(AV)} = 20A$
$t_{rr} = 20ns$

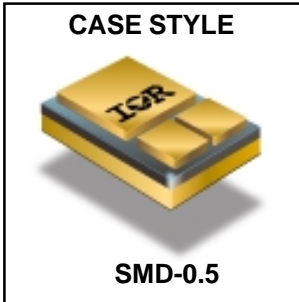
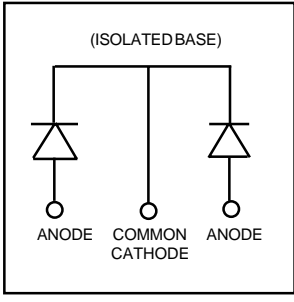
**Description**

HEXFRED™ diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and di/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

**Absolute Maximum Ratings**

	Parameter	Max.	Units
$V_R$	Cathode to Anode Voltage ( Per Leg )	200	V
$I_{F(AV)}$	Continuous Forward Current, ① $T_C = 85^\circ C$	20	A
$I_{FSM}$	Single Pulse Forward Current, ② $T_C = 25^\circ C$ ( Per Leg)	125	
$P_D @ T_C = 25^\circ C$	Maximum Power Dissipation	28	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 to +150	$^\circ C$

**Note:** ① D.C. = 50% rect. wave  
 ② 1/2 sine wave, 60 Hz , P.W. = 8.33 ms

<p><b>CASE STYLE</b></p>  <p><b>SMD-0.5</b></p>	<p>(ISOLATED BASE)</p>  <p>ANODE COMMON ANODE CATHODE</p>
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**Electrical Characteristics ( Per Leg ) @ T<sub>J</sub> = 25°C (unless otherwise specified)**

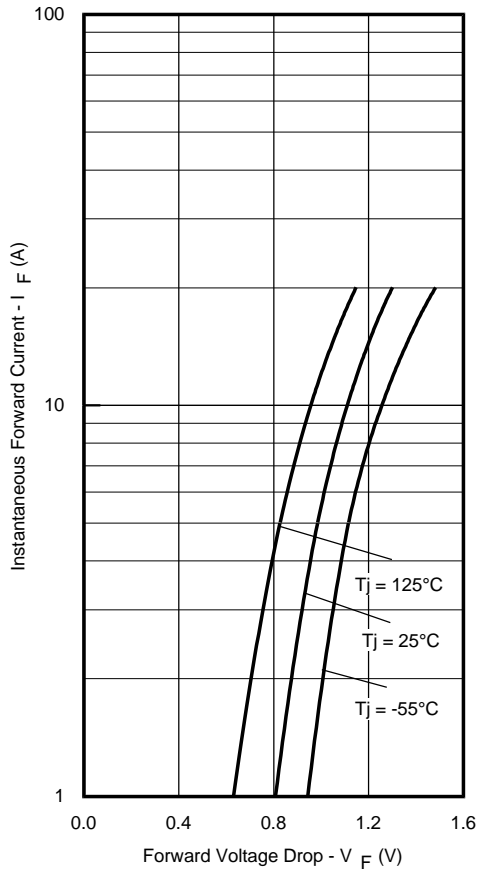
	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V <sub>BR</sub>	Cathode Anode Breakdown Voltage	200	—	—	V	I <sub>R</sub> = 100μA
V <sub>F</sub>	Forward Voltage See Fig. 1	—	—	1.26	V	I <sub>F</sub> = 10A, T <sub>J</sub> = -55°C
		—	—	1.11		I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C
		—	—	1.30		I <sub>F</sub> = 20A, T <sub>J</sub> = 25°C
		—	—	0.96		I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C
I <sub>R</sub>	Reverse Leakage Current See Fig. 2	—	—	10	μA	V <sub>R</sub> = V <sub>R</sub> Rated
		—	—	1.0	mA	V <sub>R</sub> = V <sub>R</sub> Rated, T <sub>J</sub> = 125°C
C <sub>T</sub>	Junction Capacitance, See Fig. 3	—	—	20	pF	V <sub>R</sub> = 200V
L <sub>S</sub>	Series Inductance	—	4.8	—	nH	Measured from center of cathode pad to center of anode pad

**Dynamic Recovery Characteristics ( Per Leg ) @ T<sub>J</sub> = 25°C (unless otherwise specified)**

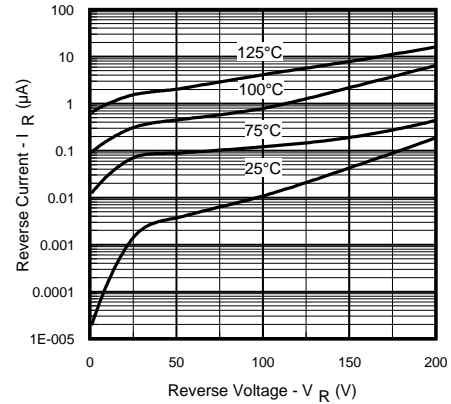
	Parameter	Min.	Typ.	Max.	Units	Test Conditions
t <sub>rr</sub>	Reverse Recovery Time	—	—	20	ns	I <sub>F</sub> = 1.0A, V <sub>R</sub> = 30V, di <sub>F</sub> /dt = 200A/μs
t <sub>rr1</sub>	Reverse Recovery Time	—	27	—	ns	T <sub>J</sub> = 25°C See Fig. 5
t <sub>rr2</sub>		—	42	—		T <sub>J</sub> = 125°C
I <sub>RRM1</sub>	Peak Recovery Current	—	3.5	—	A	T <sub>J</sub> = 25°C See Fig. 6
I <sub>RRM2</sub>		—	5.5	—		T <sub>J</sub> = 125°C
Q <sub>rr1</sub>	Reverse Recovery Charge	—	54	—	nC	T <sub>J</sub> = 25°C See Fig. 7
Q <sub>rr2</sub>		—	120	—		T <sub>J</sub> = 125°C
di <sub>(rec)M</sub> /dt1	Peak Rate of Fall of Recovery Current During t <sub>b</sub>	—	640	—	A/μs	T <sub>J</sub> = 25°C See Fig. 8
di <sub>(rec)M</sub> /dt2		—	850	—		T <sub>J</sub> = 125°C

**Thermal - Mechanical Characteristics**

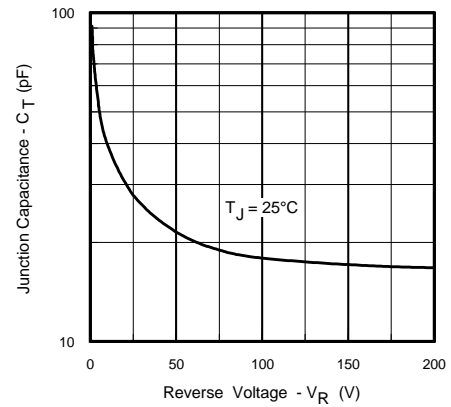
	Parameter	Typ.	Max.	Units
R <sub>thJC</sub>	Junction-to-Case, Single Leg Conducting	—	4.5	°C/W
Wt	Weight	1.0	—	g



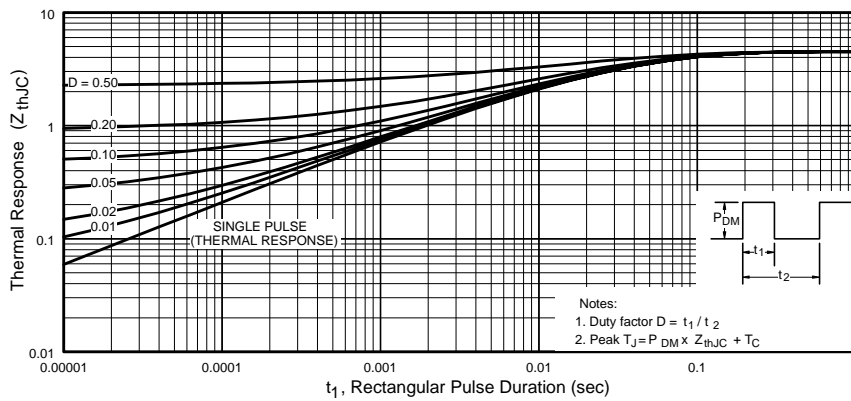
**Fig. 1** - Maximum Forward Voltage Drop Vs. Instantaneous Forward Current ( Per Leg )



**Fig. 2** - Typical Reverse Current Vs. Reverse Voltage ( Per Leg )



**Fig. 3** - Typical Junction Capacitance Vs. Reverse Voltage ( Per Leg )



**Fig. 4** - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics ( Per Leg )

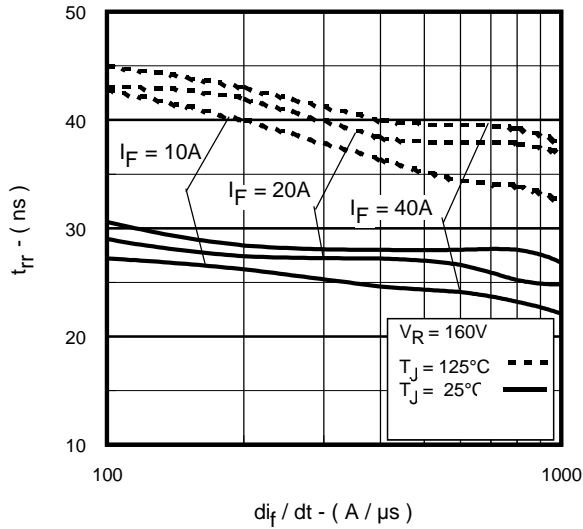


Fig. 5 - Typical Reverse Recovery Vs.  $di/dt$ , ( Per Leg )

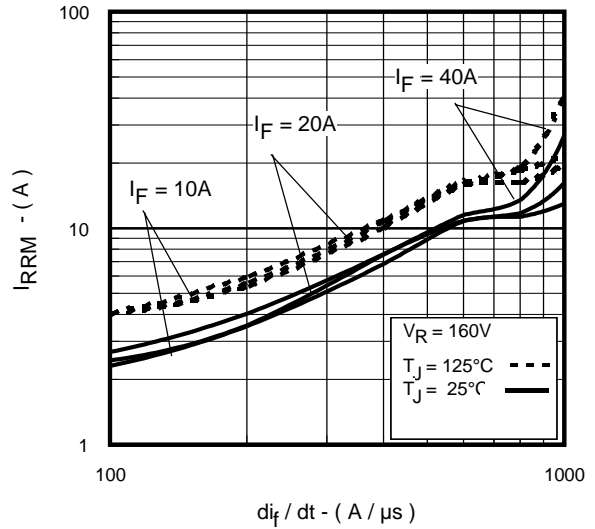


Fig. 6 - Typical Recovery Current Vs.  $di/dt$  ( Per Leg )

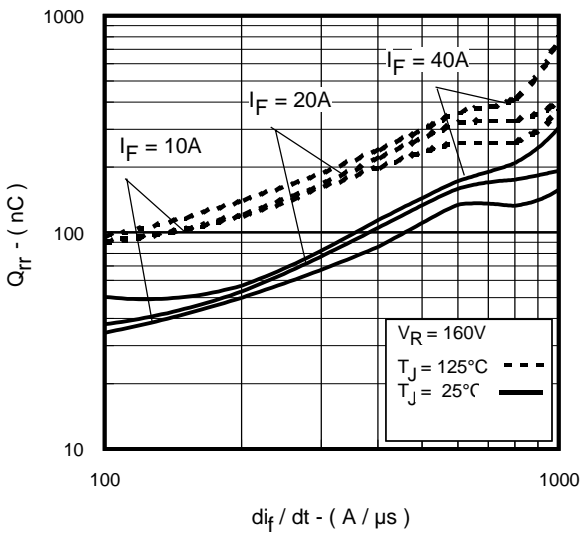


Fig. 7 - Typical Stored Charge Vs.  $di/dt$  ( Per Leg )

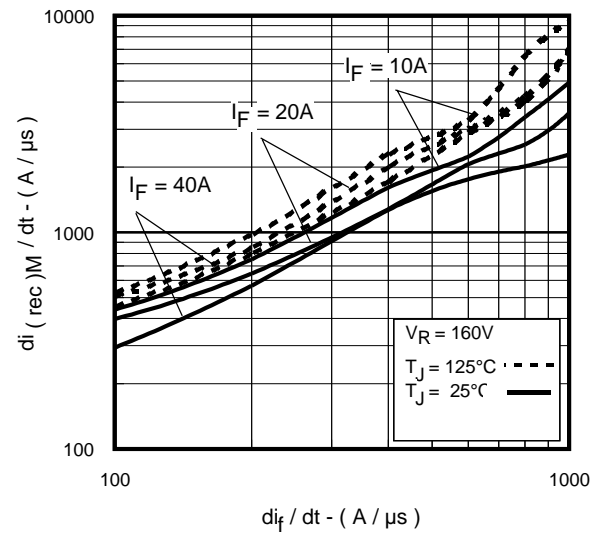


Fig. 8 - Typical  $di_{(rec)M}/dt$  Vs.  $di/dt$  ( Per Leg )

